NSN 5961-00-752-0150



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-752-0150 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 1.00 microamperes zero-gate-voltage source current preset and 150.00 milliamperes source cutoff current blank **Power Rating Per Characteristic:** 600.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminals silver and terminal surfaces gold **Precious Material:** Silver and gold **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life:

Demilitarization: No

Unit Of Measure:

N/a

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